Odd characteristics of Au film on pentacene

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Anomalies of Au film formed on the pentacene surface are investigated as a counterpart of pentacene/Au structure. The Au film is found to contain pentacene derivatives originated from the pentacene layers, and it is composed of grains of various sizes formed as the Au thickness increases. The authors suggest that this is abundance of peculiarities of the Au film that accounts for the attenuated density of states in the valence band. Deformation of Au grains is accompanied by the lift of the pentacene layers, which, in turn, brings about the device failure. © 2007 American Institute of Physics. [DOI: 10.1063/1.2748334]

Substantial progress has been made in electronic devices based on organic semiconductors, and this has motivated a renewal in fundamental research on key factors governing the device performance.1–4 The Au/pentacene interface has been attracting attention because it differs in electrical behavior from the pentacene/Au interface.5–9 The asymmetric nature of metal/organic and organic/metal structures has been utilized in developing the memory device.8 A number of studies have been conducted on the interesting adsorption mechanism of the organic molecules on the metal. As a result much detailed information is available on the pentacene/Au interface.10,11 In the case of the Au/pentacene interface, however, only a few phenomena have been reported such as diffusion of Au into the pentacene layers, unexpected carbon atoms on the Au film, and variation of device performance depending on the Au deposition conditions.5,6

This letter shows that the electronic structures near the Fermi level of the Au/pentacene surface are different from those of the Au/SiO₂ surface. We confirmed that anomalies in the electronic structures of the Au/pentacene surface are caused by the unexpected carbon atoms and irregular morphologies concurrently observed in the Au film. The origin of the carbon species is investigated using synchrotron radiation spectroscopy and calculations based on Fick’s second law. The microscopic analysis shows that the Au film at various thicknesses has different morphologies resulting from the relaxation of the intergranular, interlayer stresses and thermal contraction during the process of cooling down the sample after Au deposition. The deformation of the Au grains resulting from the relaxation of stresses lifts the pentacene layers from beneath the Au film.

The sample preparations and spectroscopic measurements were carried out at 4B1 Beamline of Pohang Accelerator Laboratory in Korea.12 The flux of the thermally evaporated pentacene molecules and Au atoms was controlled to be 0.2 Å/s by using the thickness monitor. The valence band spectra and the secondary cutoff were acquired by the ultraviolet source (He I line). Near edge x-ray absorption fine structure (NEXAFS) measurements in partial partial electron yield mode were performed by counting the carbon KLL Auger electrons. The unloaded samples were characterized by scanning electron microscopy (SEM) (JEOL JSM-7401F), atomic force microscopy (AFM) (PSIA XE-100), and transmission electron microscopy (TEM) (JEOL JEM-3011).

Figure 1(a) shows the valence band spectra from the Au film on the SiO₂ and the pentacene surfaces. All the spectra were normalized to equalize the intensity at 9 eV. The overall spectrum of the Au/SiO₂ surface is very similar to that of the Au (111) surface.13 The features marked by B₁, B₂, and B₃ stand for the upper Au 5d bulk bands, and S₁ and S₂ are surface states.13 In the spectrum of the Au 4 Å/pentacene surface, broad features originated from the Au film begin to appear. Although Au is sufficiently thicker than the photoelectron spectroscopy probing depth, no prominent peak development is observed in the spectrum of the Au 600 Å/pentacene surface. Because of such broadness and low intensity of the spectral features, it is hard to discern the detailed peaks. These broad features are related to the density of defects and mixed surfaces that have different surface indices. Figure 1(b) shows the work function shifts recorded.

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on the pentacene/Au surface as the thickness of pentacene increases and those recorded on the Au/pentacene/SiO$_x$ surface as the thickness of Au increases. At the initial stage of pentacene deposition on the Au surface, the work function was abruptly lowered by approximately 1.1 eV and became saturated after 5 Å. In Fig. 1(b), the work function changes in the reversed structure are represented by filled stars. Although the Au thickness on the pentacene surface reaches 3800 Å, the work function of the Au film does not return to zero. Instead, it records 0.7 eV, which is lower than that of the pure Au film. These results agree with the previous research.

To explore the origins of the asymmetric behavior, the Au film on the pentacene surface was carefully re-investigated as a function of the Au thickness by using the spectroscopic and microscopic methods. As mentioned above, the valence band spectra of the Au/pentacene/SiO$_x$ surface indicated the presence of the high density of defects. Park et al. have reported the unexpected carbon on the Au film whose origin was unclear.

Figure 2(a) shows the NEXAFS spectra of the pentacene 200 Å/SiO$_x$, and Au 200 Å/pentacene 200 Å/SiO$_x$ surfaces. In the spectrum of the Au/pentacene/SiO$_x$ surface, the sharp feature at 286 eV and the broad features in the region of 290–315 eV coincide with the π$^*$ resonance peak excited from the C 1s level to LUMO+1 (lowest unoccupied molecular orbital) and also with the σ$^*$ resonances in the pentacene film. One difference is the disappearance of the peak at 284 eV attributed to the excitation from the C 1s level to LUMO. The LUMO has been reported to be localized at outer carbon atoms that compose the pentacene molecule. This means that the resonance peak at 284 eV is easily affected by foreign species generated during chemical reactions. This also means that the disappearance of the peak is attributed to the affluent Au atoms that surround the pentacene molecules on the surface. These results indicate that the unexpected carbon atoms on the Au/pentacene/SiO$_x$ surface are originated from the pentacene layers beneath the Au film rather than from external sources.

The most probable origin of the pentacene derivatives in the Au film is readesorption of the pentacene molecules in the gas phase around the sample induced by the hot Au atoms while exposing the pentacene surface to the Au flux. This suggestion is supported by the fact that the pentacene molecules desorb above 340 K and that the temperature of the pentacene/SiO$_x$ sample reached up to 360 K during Au evaporation. However, the outdiffusion of the pentacene molecules through the imperfect Au film is another pathway that needs to be considered. To test the possibility of the outdiffusion, the behavior of the C 1s level intensity on the varied thickness of the Au film was compared with the calculated value by using the redistribution diffusion model based on Fick’s second law, in which the carbon concentration at $Z_0$ (Au thickness) $= 0$ decreases as diffusion time increases. The intensity of the C 1s level can be expressed as

$$I_c \propto n_c(\lambda - Z) + \int_{Z}^{Z_0} n_c(Z) dZ,$$

where $n_c$ is the density of carbon in the pentacene layers, $n_c$ is the density of diffused carbon in the Au bulk, and $\lambda$ is the electron mean free path. For $Z < \lambda$, $I_c$ is dominated by the first term in Eq. (1). The first term goes to zero when $Z$ approaches $\lambda$, which corresponds to the initial steep slope in Fig. 2(b) and reveals $\lambda \approx 10$ Å. For $Z > \lambda$, $I_c$ is described by the second term in Eq. (1) as

$$I_c \propto \int_{Z-\lambda}^{Z} n_c(Z,t) dZ.$$

The solution of the redistribution diffusion model based on Fick’s second law is given by

$$n_c(Z,t) = (Q_0/\sqrt{\pi Dt}) \exp\left(-Z^2/4Dt\right),$$

where $D$ is the diffusion coefficient and $Q_0$ (at/cm$^3$) is the total dose. Because the diffusion process is most activated during Au evaporation when the sample temperature is elevated up to 360 K, the diffusion time was estimated by dividing the Au thickness by the Au flux. Then, by using $t = Z/(0.2 \text{ A/s})$ and $n_c(Z,t) = n_c(Z-\lambda, t)$, Eq. (2) gives $I_c \propto (1/\sqrt{Z}) \exp(-Z/20D)$. This equation was used to fit the experimental data as depicted in the inset of Fig. 2(b), in which the solid curve is obtained when $D = 2.16 \times 10^{-15}$ cm$^2$/s. This value is unusually high because it is close to that of a single carbon atom in the iron bulk. These results show that outdiffusion is not a major mechanism which brings pentacene molecules to the Au surface.

Figure 3 shows the images photographed by using the SEM, AFM, and TEM. The SEM images indicate that the morphology depends on the thickness of the Au film on the pentacene surface. Uniform surface images are observed at 300 and 400 Å of Au, whereas coarse surface images are
observed at 200 and 600 Å. Figures 3(a) and 3(b) show the best and the worst surface images at 300 and 600 Å, respectively. The AFM image taken from the Au 300 Å/pentacene surface clearly shows the distribution of grains, while the uniform surface is observed by the SEM. The grains and defects in the surface indicate mixed surfaces with different surface indices as well as uneven height, which explains why the features in the valence band spectra from the Au film on the pentacene surface are broader than those of the Au crystal.13 The protrusions shown in (c) and (f) correspond to the disordered defects in (b). The cross section of the protrusion on the Au 600 Å/pentacene surface is shown in Fig. 3(g) by utilizing the TEM. In Fig. 3(g), a feature marked by a circle shows the lift of the pentacene layers that resulted from the deformation of Au grains. As the thickness of the Au film increases, the intrinsic and external stresses accumulate. When the sample starts to cool down after the Au evaporation, a thermal stress is produced from the different coefficients of thermal expansion between the Au film and pentacene. A relaxation of the accumulated stresses induces deformation, as depicted in Fig. 3(h). This is an example of the device failure that occurs due to the preparation method of the metal contact. Accordingly, the molecular devices composed of only several molecular layers are expected to be more susceptible to failure.

In summary, pentacene derivatives are observed in the Au film on the pentacene surface. The spectroscopic results and the calculations based on Fick’s second law indicate that the major origin of the pentacene derivatives is desorption of the desorbed pentacene molecules caused by hot Au atoms. A microscopic analysis showed that the deformation of the Au grains is caused by the relaxation of accumulated stresses that accompanies the lift of the pentacene layers beneath the Au film. Pentacene derivatives and coarse morphologies observed on the Au film are suggested as causes of valence band broadening.

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